



BROWN

Nanosystem Design Lecture 1: Introduction

Prof. R. Iris Bahar
EN291-S10

September 6, 2005

Course Information

- Instructor: Iris Bahar
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- Office Hours: By appointment
- Course Webpage:
<http://www.lems.brown.edu/~iris/en291s10-05>
(soon to be up and running)



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Course Format and Grading

- Seminar format: mix of lectures and discussion on assigned reading.
- Students are responsible for leading and participating in these discussions.
- Grading:
 - Discussion leadership: 20%
 - Quality of scribe: 20%
 - Class participation: 15%
 - Research project: 35%
 - Homework: 10%



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Class Discussions

- Most classes will consist of a discussion of 1-2 papers on:
 - Nanotechnology
 - Alternative approaches to computing
- Class format
 - 1 discussion leader: keep discussion going, preparing presentation material
 - 2 scribes: create notes of the lecture. These will be posted on the webpage for all the class to access.
 - **All students:** be involved in active discussion



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Project

- Projects will involve investigating some aspect of nanotechnology or non-conventional computing
- May be related to some topic discussed in class or something new.
- Expected to involve new research – not just a survey of previous work.
- Group projects are encouraged



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What is this course about?

- A look at how improvements in silicon fabrication technology have shaped today's computer system designs.
- Understanding the limitations of today's silicon-based technology
- Exploring emerging nanotechnologies
- Understanding how these alternative technologies may impact future VLSI and computer architectures.



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What about CS 295??

- Prof. Savage is offering a course on nanocomputing (Introduction to Nanocomputing)
- While some of the same topics will be covered in both courses, the emphasis will be different.
- EN291 will emphasize more of the device and design aspects of nanocomputing
- CS 295 will emphasize more of an analytical approach.
- Some students may wish to register for both courses.



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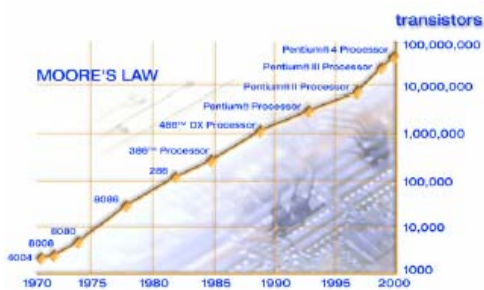
Computing today

- Over the past decades, computer system performance has been driven by improvements in silicon fabrication technology.
- In 1973, Gordon Moore first made the prediction that the number of transistors on a chip would double every 18 months until fundamental physical limits are reached.



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Moore's Law in action



From <http://www.intel.com/technology/moorslaw.htm>



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What next?

- Signs are that the rate of improvement cannot be sustained.
- Maintaining the exponential growth rate is becoming increasingly difficult.
- Will “conventional” silicon-based architectures need to be replaced with “unconventional” structures to maintain growth?



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Conventional vs. Unconventional

- “Conventional” computer architecture
 - Uses stored-program model of computation
 - Implemented using silicon VLSI
- Unconventional computer architecture
 - ASICs
 - Reconfigurable devices
 - Quantum
 - Biological
 - Molecular Electronics




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Stored-Program Model

- One of the key developments in early computing.
 - Also known as the “von Neumann” model

```
for (i=1; i<10; i++) {  
    a = a * g(i);  
}
```



```
01110110110110  
11111011011011  
01101000010110  
10110101110110  
10010110111010
```



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The Stored-Program Model

- **Treat programs as data**
 - Load and store them from disk
 - Programs can modify themselves
 - Programs can modify/create other programs
 - Assemblers
 - Compilers
 - debuggers
- **Universal computing devices**



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Disadvantages of this Model

- Big complexity/computational power cost needed to provide flexibility
- A single application can rarely take advantage of all features available on these devices
- May still not be able to do specific tasks very efficiently.



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Alternatives

- **Dataflow**
 - Instructions explicitly encode dependencies
 - Goal is to expose fine-grained parallelism
 - Really an alternate form of stored program
- **Embedding Computation In Hardware**
 - ASICs
 - Reconfigurable Logic



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Why (silicon-based) alternatives?

- **Growth of embedded systems**
 - Flexibility less key than performance and hardware efficiency
 - hand-designed ASICs are quite popular
 - FPGAs improving in performance and density
- **Changing application domain**
 - Multi-phased streaming applications



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Silicon VLSI

- **Geometric scaling in density/speed**
 - 50%/year increase in density
 - 35-50%/year increase in system performance
- **Low cost, high reliability, acceptable yield**
- **Improved transistor fabrication techniques**
 - e.g., SOI reduces junction cap, allows for reduced voltage



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Silicon VLSI (cont.)

- **Supply voltage**
 - Reduction in each process generation reduces power, and improves switching speeds.
- **Integration creates new possibilities**
 - Tremendous jump in system performance with each level of integration.
 - Mixed-mode system-on-a-chip (SoC) products



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Limitations of Silicon

- Currently based on optical lithography
 - Must move to extreme UV or x-rays to improve pattern resolution
- Transistors are bulk devices
 - Rely on having many atoms in each region
 - Becomes impossible to lightly dope regions close to 10nm feature size



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Limitations of Silicon (cont.)

- Interconnects
 - Don't scale well with process shrink (relative delay increases)
 - Becoming a limiting factor in system speed.
 - Approaching 85% of overall delay
- Supply voltage
 - Using lower voltage reduces noise margins.



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Non-Silicon Alternatives

- Molecular/Quantum Electronics
 - Essentially replace FETs with other devices that have similar behavior
- Carbon Nanotubes
 - Can get switch-like behavior, make wires
- Quantum Computing
 - Expose quantum effects to the programming model
 - Offers potential for performance that's impossible in conventional systems
- Biological Computing
 - Biological reactions mimic Boolean logic gates
 - Very slow, but may be useful for medical applications



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